# Supporting Information

Imparting CO<sub>2</sub> reduction selectivity to ZnGa<sub>2</sub>O<sub>4</sub> photocatalysts by crystallization from hetero nano assembly of amorphous-like metal hydroxides.

Masanori Takemoto, Yasuaki Tokudome\*, Soichi Kikkawa, Kentaro Teramura\*, Tsunehiro Tanaka, Hidenobu Murata, Atsushi Nakahira, Kenji Okada and Masahide Takahashi \*corresponding authors

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## Experimental

#### Solid state reaction

The synthesis was performed according to a previous-reported  $ZnGa_2O_4$  synthesis.<sup>1</sup> ZnO (0.65 g),  $Ga_2O_3$  (1.50 g) and deionized water (2.5 mL) were mixed in a mortar for 30 min to yield homogeneous slurry. The slurry was dried in oven at 80 °C for 15 min. 1 mL of deionized water was added to the dried powder and the slurry was mixed for 30 min. Then, the slurry was dried in oven at 80 °C for 1 h, and calcined at 700 °C or 850 °C for 12 h.

## Characterization

#### Electric conductivity measurement

The total amount of ionic species  $(Zn^{2+} + Ga^{3+})$  consumed to yield metal hydroxide through the alkalization by epoxide ring-opening was calculated from an electric conductivity measurement according to the previous report. <sup>2</sup> The solution at a molar ratio of  $Zn(NO_3)_2 \cdot 6H_2O$ :  $Ga(NO_3)_3 \cdot nH_2O$ : ultra-pure water: ethanol: PO = 1: 2: 134: 66: 45 was measured. The data was collected at 24 h after the addition of PO to the precursor solution.

#### Calculation of crystalline size of ZnGa<sub>2</sub>O<sub>4</sub> catalysts

Crystallite size of ZnGa<sub>2</sub>O<sub>4</sub> was calculated using Scherrer's equation by reference to the previous reports,<sup>3,4</sup>  $D = K\lambda/(Bcos\theta)$ . Here, *K* is a constant (0.9),  $\lambda$  is the wavelength of CuK $\alpha$  radiation (0.154 nm), *B* is the Full Width of Half Maximum (FWHM) of the diffraction peak centered at 35.73 °, and  $\theta$  is Bragg's angle.

### X-ray photoelectron spectroscopy (XPS) of $ZnGa_2O_4$ catalysts

Powderly sample was molded into a pellet ( $\varphi = 7$  mm). The pellet was mounted on the sample holder by using conductive carbon tape. All the binding energies were refereced to the C 1s peak at 284.8 eV of the surface adventitious carbon. The surface atomic ratio (Zn/Ga) was calculated from the integrated intensity of Zn 2p<sub>3/2</sub> and Ga 2p<sub>3/2</sub> spectra by using corrsponding relative sensitivity factors.

(a) Precursory gel



Figure S1 (a) FE-TEM image of precursory wet gel obtained from an aqueous solution of  $Zn(NO_3)_2 \cdot 6H_2O$  and  $Ga(NO_3)_3 \cdot nH_2O$  under a highly supersaturated condition induced by epoxide-mediated alkalization. Enlarged views and EDS mappings of Zn and Ga of (b) Layered Double hydroxide and (c) Amorphous Metal Hydroxide as shown in Fig. S1(a).



Figure S2 Calibration curve for determining the amount of comsumed ionic species druing the precipitation of hydroxides. The calibration is  $log_{10}(\sigma) = 0.74064 \times log_{10}(C_{Zn+Ga})$  + 1.59517, where  $\sigma$  and  $C_{Zn+Ga}$  are the conductivity of the solution and the total concentration of metal ions ( $Zn^{2+} + Ga^{3+}$ ), respectively. The value of conductivity of the reacting solution at 24 h is 2.42 mS cm<sup>-1</sup>, corresponding to 0.0231 M, where 96.3% of ionic species are consumed to precipitate hydroxides.



Figure S3 SEM images of AMH-derived ZnGa<sub>2</sub>O<sub>4</sub> catalysts.



Figure S4 PXRD patterns of  $ZnGa_2O_4$  prepared from a mixture of ZnO and  $Ga_2O_3$ powders by calcination at 850 °C.  $ZnGa_2O_4$  obtained as a single phase was named as "standard  $ZnGa_2O_4$ ". Crystallite size and BET specific surface area of standard  $ZnGa_2O_4$  are 29 nm and 1.3 m<sup>2</sup> g<sup>-1</sup>, respectively.



Figure S5 Wide scan XPS spectra of AMH-derived  $ZnGa_2O_4$ -700 (red line) and standard  $ZnGa_2O_4$  (black line).



Figure S6 Rates of  $H_2$  (grey),  $O_2$  (sky blue), and CO (red) evolution and reaction selectivity toward CO evolution ( $\blacklozenge$ ) over Ag-loaded AMH-derived ZnGa<sub>2</sub>O<sub>4</sub> prepared by calcination at various temperatures for 12 h; the loading amount of Ag co-catalyst: 1.0wt%.



Figure S7 Time course of gas evolutions for photocatalytic conversion of CO<sub>2</sub> with H<sub>2</sub>O over bare AMH-derived ZnGa<sub>2</sub>O<sub>4</sub>-700.



Figure S8 PXRD pattern of AMH-derived ZnGa<sub>2</sub>O<sub>4</sub>-700 after the photocatalytic CO<sub>2</sub> reduction in water.



catalyst	Temperature / °C	E <sub>g</sub> / eV
AMH-derived ZnGa <sub>2</sub> O <sub>4</sub>	700	4.8
	800	4.7
	900	4.7
Standard ZnGa <sub>2</sub> O <sub>4</sub>	850	4.7

Figure S9 UV-Vis spectra and estimated  $E_g$  values of ZnGa<sub>2</sub>O<sub>4</sub> catalysts (without Ag cocatalyst). There can be seen no dependence of the optical absorption property of ZnGa<sub>2</sub>O<sub>4</sub> catalysts ( $E_g$ : 4.6 - 4.8 eV) on the resultant catalytic activities. Catalysts after photocatalytic reaction were collected and measured.

Table S1 Base strength, crystallite size and specific surface area of bare AMH-derived ZnGa<sub>2</sub>O<sub>4</sub> and standard ZnGa<sub>2</sub>O<sub>4</sub>.

Photocatalyst	Precursor	Temperature [°C]	Crystallite size [nm]	Specific surface area [m <sup>2</sup> g <sup>-1</sup> ]	Base strength
AMH-derived ZnGa₂O₄	Zn-Ga AMH	500	6.9	26	15 < H_
		600	13	15	15 < H_
		700	20	5.0	9.8 < H_ < 15
		800	25	4.7	9.8 < H_ < 15
		900	39	0.53	9.8 < H_ < 15
Standard ZnGa <sub>2</sub> O <sub>4</sub>	ZnO + Ga <sub>2</sub> O <sub>3</sub>	850	29	1.3	H_ < 7.2

Table S2 Summary of crystallite size, specific surface area and reaction selectivity toward CO evolution in photocatalytic conversion of CO<sub>2</sub> with H<sub>2</sub>O of bare ZnGa<sub>2</sub>O<sub>4</sub> catalysts.

Photocatalyst	Temperature [°C]	Crystallite size [nm]	Specific surface area [m² g⁻1]	Reaction selectivity toward CO evolution [%]
AMH-derived ZnGa₂O₄	700	20	5.0	48.0
	800	25	4.7	40.3
	900	39	0.53	47.3
Standard ZnGa <sub>2</sub> O <sub>4</sub>	850	29	1.3	20.3

# Reference

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